

PROTECTION PRODUCTS
Description

RailClamps are surge rated diode arrays designed to protect high speed data interfaces. The SR series has been specifically designed to protect sensitive components which are connected to data and transmission lines from overvoltage caused by electrostatic discharge (**ESD**), electrical fast transients (**EFT**), and tertiary **lightning**.

The unique design of the SR series devices incorporates four surge rated, low capacitance steering diodes, and a TVS diode in a single package. The TVS diode is constructed using Semtech's proprietary low voltage EPD technology for superior electrical characteristics at 2.8 volts.

During transient conditions, the steering diodes direct the transient to either the positive side of the power supply line or to ground. The internal TVS diode prevents over-voltage on the power line, protecting any downstream components.

The low capacitance array configuration allows the user to protect two high-speed data or transmission lines. The low inductance construction minimizes voltage overshoot during high current surges.

Features

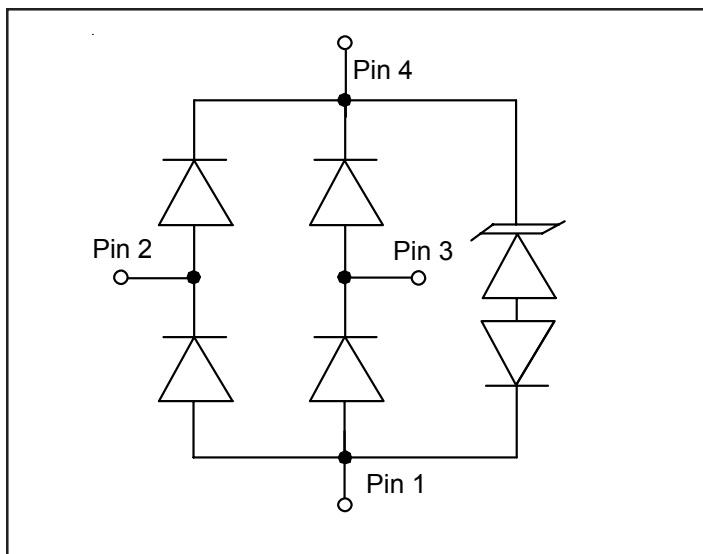
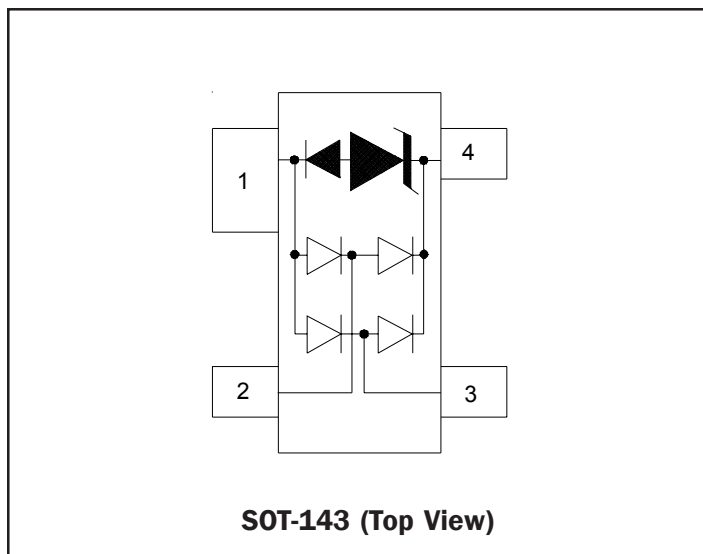
- ◆ ESD protection to
IEC 61000-4-2 (ESD) $\pm 15\text{kV}$ (air), $\pm 8\text{kV}$ (contact)
IEC 61000-4-4 (EFT) 40A (5/50ns)
IEC 61000-4-5 (Lightning) 12A (8/20 μs)
- ◆ Array of surge rated diodes with internal EPD TVS™ diode
- ◆ Protects two I/O lines
- ◆ Low capacitance (<10pF) for high-speed interfaces
- ◆ Low leakage current (< 1 μA)
- ◆ Low operating voltage: 2.8V
- ◆ Solid-state technology

Mechanical Characteristics

- ◆ JEDEC SOT-143 package
- ◆ Molding compound flammability rating: UL 94V-0
- ◆ Marking : R2.8
- ◆ Packaging : Tape and Reel

Applications

- ◆ Firewire
- ◆ Sensitive Analog Inputs
- ◆ Video Line Protection
- ◆ Portable Electronics
- ◆ Microcontroller Input Protection
- ◆ WAN/LAN Equipment

Circuit Diagram

Schematic & PIN Configuration


PROTECTION PRODUCTS
Absolute Maximum Rating

Rating	Symbol	Value	Units
Peak Pulse Power ($t_p = 8/20\mu s$)	P_{pk}	200	Watts
Peak Pulse Current ($t_p = 8/20\mu s$)	I_{pp}	14	A
Peak Forward Voltage ($I_F = 1A$, $t_p = 8/20\mu s$)	V_{FP}	1.5	V
Lead Soldering Temperature	T_L	260 (10 sec.)	°C
Operating Temperature	T_J	-55 to +125	°C
Storage Temperature	T_{STG}	-55 to +150	°C

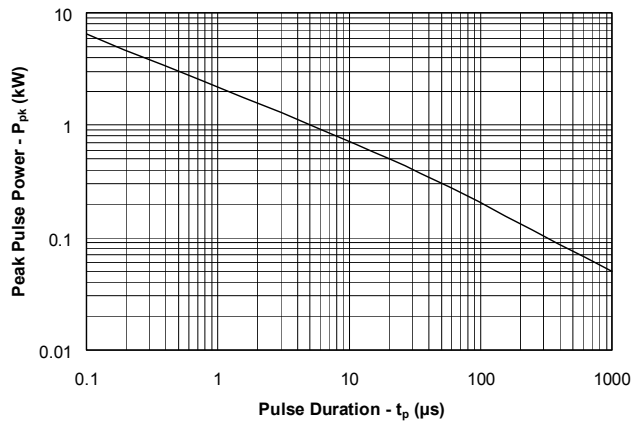
Electrical Characteristics

SR2.8						
Parameter	Symbol	Conditions	Minimum	Typical	Maximum	Units
Reverse Stand-Off Voltage	V_{RWM}				2.8	V
Punch-Through Voltage	V_{PT}	$I_{PT} = 2\mu A$	3.0			V
Snap-Back Voltage	V_{SB}	$I_{SB} = 50mA$	2.8			V
Reverse Leakage Current	I_R	$V_{RWM} = 2.8V$, $T = 25^\circ C$			1	μA
Clamping Voltage	V_C	$I_{pp} = 1A$, $t_p = 8/20\mu s$			5.0	V
Clamping Voltage	V_C	$I_{pp} = 5A$, $t_p = 8/20\mu s$			8.5	V
Junction Capacitance	C_j	Between I/O pins and Ground $V_R = 0V$, $f = 1MHz$		6	10	pF
		Between I/O pins $V_R = 0V$, $f = 1MHz$		3		pF

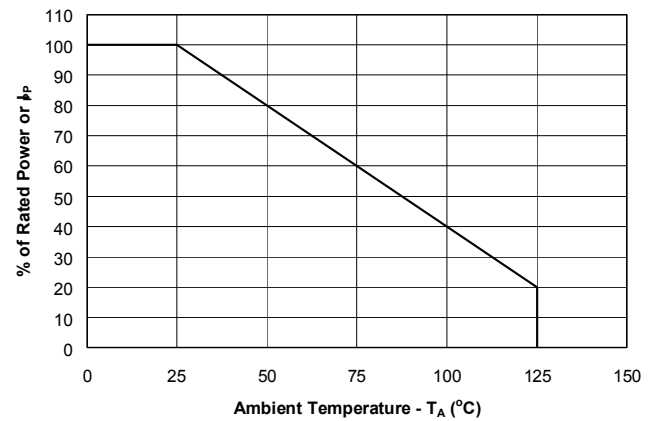
PROTECTION PRODUCTS

Typical Characteristics

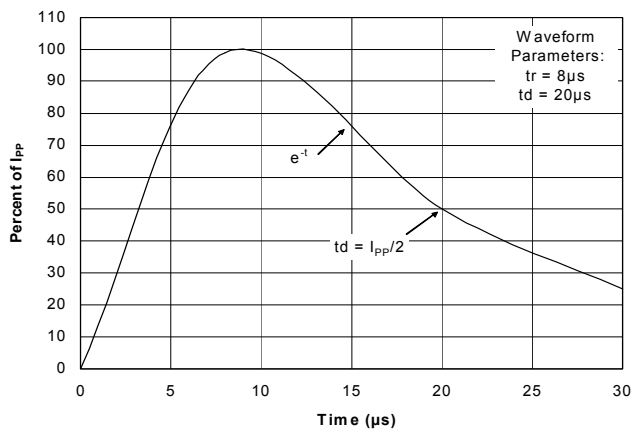
Non-Repetitive Peak Pulse Power vs. Pulse Time



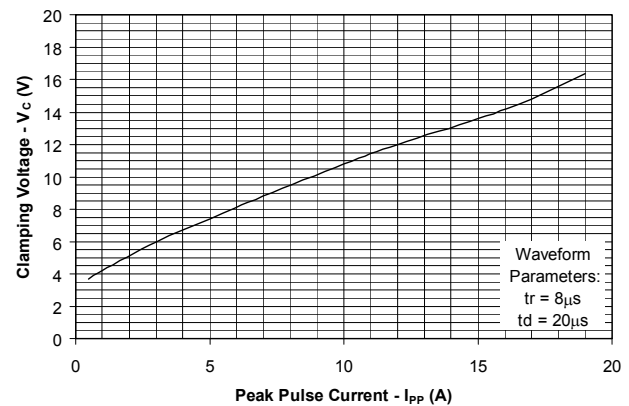
Power Derating Curve



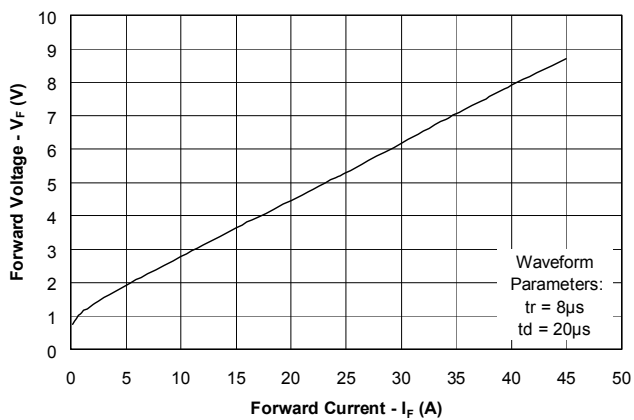
Pulse Waveform



Clamping Voltage vs. Peak Pulse Current



Forward Voltage vs. Forward Current



PROTECTION PRODUCTS

Applications Information

Device Connection Options for Protection of Two High-Speed Data Lines

The SR2.8 TVS is designed to protect two data lines from transient over-voltages by clamping them to a fixed reference. When the voltage on the protected line exceeds the reference voltage (plus diode V_F) the steering diodes are forward biased, conducting the transient current away from the sensitive circuitry. Data lines are connected at pins 2 and 3. The negative reference (REF1) is connected at pin 1. This pin should be connected directly to a ground plane on the board for best results. The path length is kept as short as possible to minimize parasitic inductance. The positive reference (REF2) is connected at pin 4. The options for connecting the positive reference are as follows:

Note that pins 4 is connected internally to the cathode of the low voltage TVS. It is not recommended that this pin be directly connected to a DC source greater than the snap-back voltage (V_{SB}) as the device can latch on as described below.

EPD TVS Characteristics

These devices are constructed using Semtech's proprietary EPD technology. By utilizing the EPD technology, the SR2.8 can effectively operate at 2.8V while maintaining excellent electrical characteristics.

The EPD TVS employs a complex npn structure in contrast to the pn structure normally found in traditional silicon-avalanche TVS diodes. Since the EPD TVS devices use a 4-layer structure, they exhibit a slightly different IV characteristic curve when compared to conventional devices. During normal operation, the device represents a high-impedance to the circuit up to the device working voltage (V_{RWM}). During an ESD event, the device will begin to conduct and will enter a low impedance state when the punch through voltage (V_{PT}) is exceeded. Unlike a conventional device, the low voltage TVS will exhibit a slight negative resistance characteristic as it conducts current. This characteristic aids in lowering the clamping voltage of the device, but must be considered in applications where DC voltages are present.

When the TVS is conducting current, it will exhibit a slight "snap-back" or negative resistance

Data Line Protection Using Internal TVS Diode as Reference

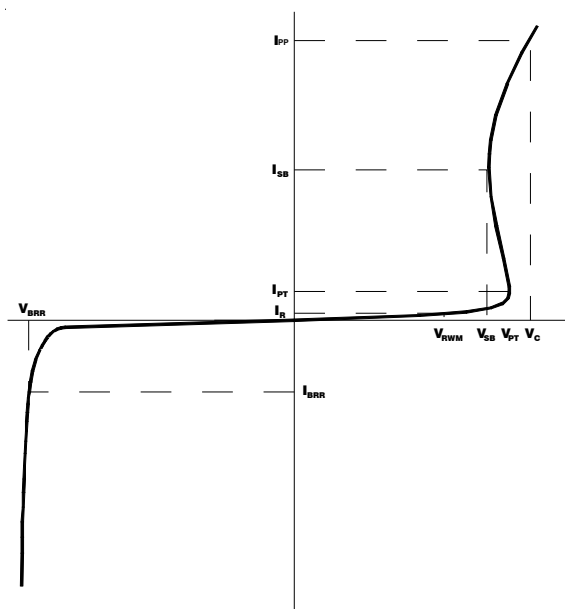
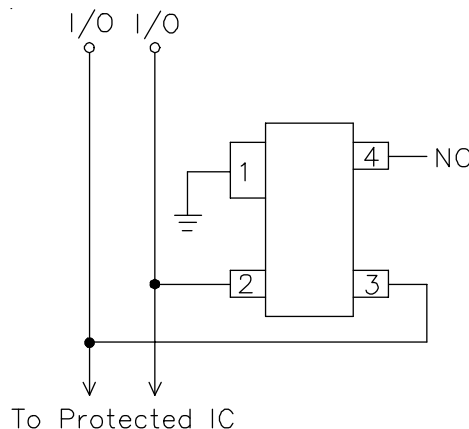


Figure 1 - EPD TVS IV Characteristic Curve

characteristics due to its structure. This point is defined on the curve by the snap-back voltage (V_{SB}) and snap-back current (I_{SB}). To return to a non-conducting state, the current through the device must fall below the I_{SB} (approximately $<50\text{mA}$) and the voltage must fall below the V_{SB} (normally 2.8 volts for a 3.3V device). If a 3.3V TVS is connected to 3.3V DC source, it will never fall below the snap-back voltage of 2.8V and will therefore stay in a conducting state.

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Applications Information (*continued*)

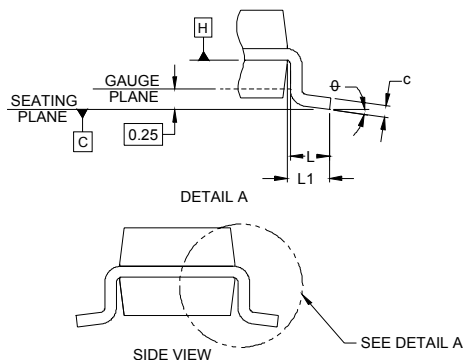
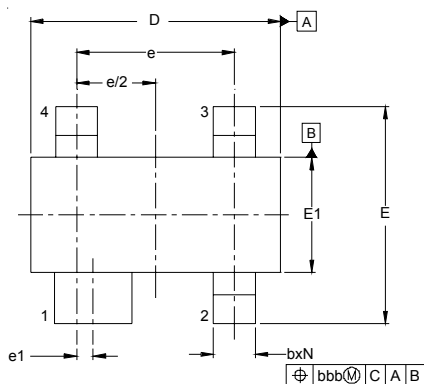
Board Layout Considerations for ESD Protection

Board layout plays an important role in the suppression of extremely fast rise-time ESD transients. Recall that the voltage developed across an inductive load is proportional to the time rate of change of current through the load ($V = L di/dt$). The total clamping voltage seen by the protected load will be the sum of the TVS clamping voltage and the voltage due to the parasitic inductance ($V_{c(TOT)} = V_c + L di/dt$). ***Parasitic inductance in the protection path can result in significant voltage overshoot, reducing the effectiveness of the suppression circuit.*** An ESD induced transient for example reaches a peak in approximately 1ns. For a 30A pulse (per IEC 61000-4-2 Level 4), 1nH of series inductance will increase the effective clamping voltage by 30V ($V = 1 \times 10^{-9} (30/1 \times 10^{-9})$). For maximum effectiveness, the following board layout guidelines are recommended:

- Minimize the path length between the SR3.3 and the protected line.
- Place the SR2.8 near the connector to restrict transient coupling in nearby traces.
- Minimize the path length (inductance) between the RJ45 connector and the SR2.8.

Matte Tin Lead Finish

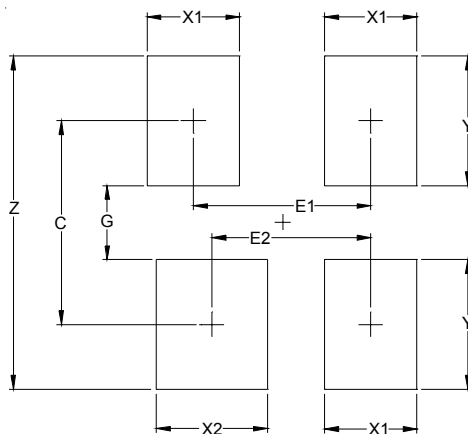
Matte tin has become the industry standard lead-free replacement for SnPb lead finishes. A matte tin finish is composed of 100% tin solder with large grains. Since the solder volume on the leads is small compared to the solder paste volume that is placed on the land pattern of the PCB, the reflow profile will be determined by the requirements of the solder paste. Therefore, these devices are compatible with both lead-free and SnPb assembly techniques. In addition, unlike other lead-free compositions, matte tin does not have any added alloys that can cause degradation of the solder joint.

PROTECTION PRODUCTS
Outline Drawing - SOT-143


DIM	INCHES			MILLIMETERS		
	MIN	NOM	MAX	MIN	NOM	MAX
A	.031	-	.048	0.80	-	1.22
A1	.000	-	.006	0.013	-	0.15
A2	.029	.035	.042	0.75	0.90	1.07
b	.011	-	.020	0.30	-	0.51
b1	.029	-	.037	0.76	-	0.94
c	.003	-	.008	0.08	-	0.20
D	.110	.114	.120	2.80	2.90	3.04
E	.082	.093	.104	2.10	2.37	2.64
E1	.047	.051	.055	1.20	1.30	1.40
e	.075	-	-	1.92	BSC	-
e1	.008	-	-	0.20	BSC	-
L	.015	.020	.024	0.40	0.50	0.60
L1	(.021)	-	-	(0.54)	-	-
N	4	-	-	4	-	-
φ	0°	-	8°	0°	-	8°
aaa	.006	-	-	0.15	-	-
bbb	.008	-	-	0.20	-	-
ccc	.004	-	-	0.10	-	-

NOTES:

1. CONTROLLING DIMENSIONS ARE IN MILLIMETERS (ANGLES IN DEGREES).
2. DATUMS **-A-** AND **-B-** TO BE DETERMINED AT DATUM PLANE **-H-**
3. DIMENSIONS "E1" AND "D" DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.
4. REFERENCE JEDEC STD TO-253, VARIATION D.

Land Pattern - SOT-143


DIMENSIONS		
DIM	INCHES	MILLIMETERS
C	(.087)	(2.20)
E1	.076	1.92
E2	.068	1.72
G	.031	0.80
X1	.039	1.00
X2	.047	1.20
Y	.055	1.40
Z	.141	3.60

NOTES:

1. THIS LAND PATTERN IS FOR REFERENCE PURPOSES ONLY
CONSULT YOUR MANUFACTURING GROUP TO ENSURE YOUR
COMPANY'S MANUFACTURING GUIDELINES ARE MET.
2. REFERENCE IPC-SM-782A.

PROTECTION PRODUCTS**Marking Codes**

Part Number	Marking Code
SR2.8	R2.8

Ordering Information

Part Number	Lead Finish	Qty per Reel	Reel Size
SR2.8.TC	SnPb	3,000	7 Inch
SR2.8.TCT	Pb Free	3,000	7 Inch

Contact Information

Semtech Corporation
Protection Products Division
200 Flynn Road, Camarillo, CA 93012
Phone: (805)498-2111 FAX (805)498-3804

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Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

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На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9